



Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	l _D max T _A = +25°C
40V	7.5mΩ @ V _{GS} = 10V	14.4A
40 V	10mΩ @ V _{GS} = 4.5V	12.5A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

POWERDI[®]3333-8

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

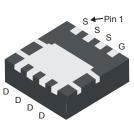
- Low R_{DS(ON)} ensures on state losses are minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product

40V N-CHANNEL ENHANCEMENT MODE MOSFET

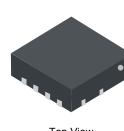
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

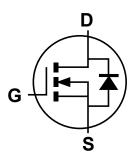
- Case: POWERDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.072 grams (approximate)



Bottom View



Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN4008LFG-7	POWERDI [®] 3333-8	2000/Tape & Reel
DMN4008LFG-13	POWERDI [®] 3333-8	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



N47= Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 13 = 2013) WW = Week code (01 ~ 53)

@T_A = +25°C, unless otherwise specified.)

DMN4008LFG

Characteristic	Symbol	Value	Units				
Drain-Source Voltage	V _{DSS}	40	V				
Gate-Source Voltage			V _{GSS}	±20	V		
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	14.4 11.6	А		
	t<10s	T _A = +25°C T _A = +70°C	ID	19.2 15.4	A		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	90	A		
Maximum Continuous Body Diode Forward Current (Note 6)			Is	3	A		
Avalanche Current, L = 0.1mH			Avalanche Current, L = 0.1mH		I _{AS}	38	A
Avalanche Energy, L = 0.1mH			E _{AS}	75	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)		PD	1.0	W	
Thermal Desistance, Junction to Ambient (Note 5)	Steady state	D	119	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	t<10s R _{0JA}		C/W	
Total Power Dissipation (Note 6)		PD	2.3	W	
Thermal Desistance, Junction to Ambient (Note 6)	Steady state	D	53	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R _{0JA}	30		
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	6.1			
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

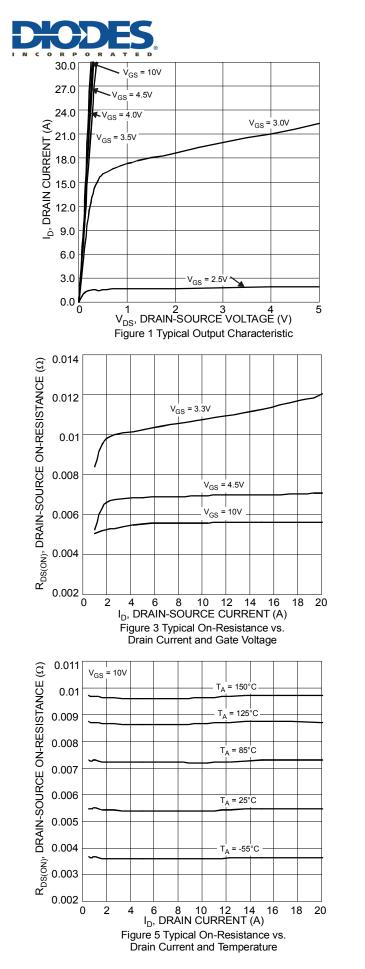
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

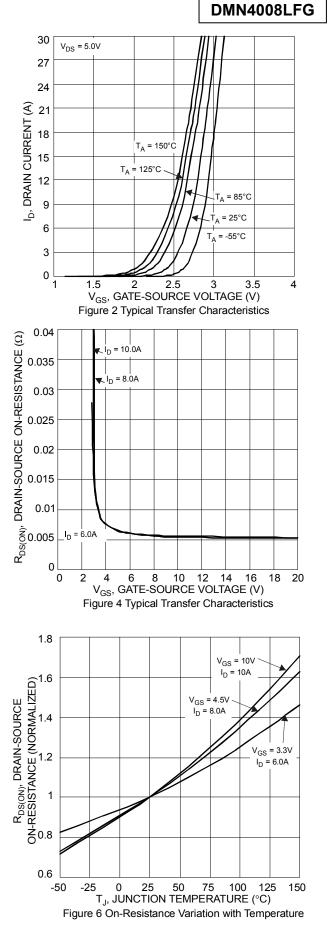
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				1		
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	—	1	μA	V _{DS} = 40V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	1	—	3	V	V_{DS} = V_{GS} , I_D = 250 μ A
		—	5.5	7.5	mΩ	V _{GS} = 10V, I _D = 10A
Static Drain-Source On-Resistance	R _{DS (ON)}	_	7	10		V _{GS} = 4.5V, I _D = 8A
		_	—	20		V _{GS} = 3.3V, I _D = 6A
Diode Forward Voltage	V _{SD}	_	0.7	1.1	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	—	3537	_	pF	
Output Capacitance	C _{oss}	_	257	—	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz
Reverse Transfer Capacitance	C _{rss}	_	215	_	pF	
Gate Resistance	Rq	_	0.9		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	34	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qq	_	74		nC	
Gate-Source Charge	Q _{qs}	_	10.2		nC	– V _{DS} = 20V, I _D = 10A
Gate-Drain Charge	Q _{gd}	_	12.5		nC	-
Turn-On Delay Time	t _{D(on)}		8.2		ns	
Turn-On Rise Time	tr	_	14.1	—	ns	V _{GS} = 10V, V _{DS} = 20V,
Turn-Off Delay Time	t _{D(off)}	_	69.7	_	ns	$R_{G} = 6\Omega, I_{D} = 10A$
Turn-Off Fall Time	tf	_	24.4	_	ns	1
Body Diode Reverse Recovery Time	trr	_	18.5	_	nS	
Body Diode Reverse Recovery Charge	Q _{rr}	_	12.0		nC	−I _F = 10A, di/dt = 100A/μs

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

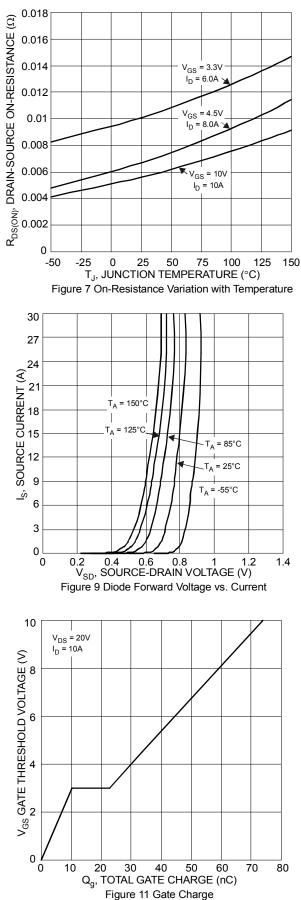


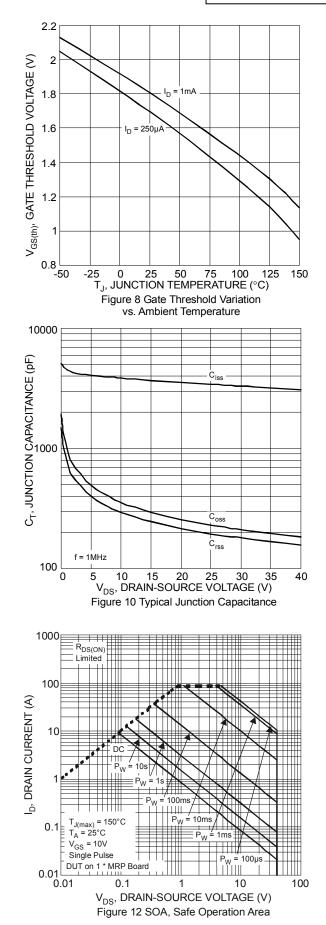


NEW PRODUCT

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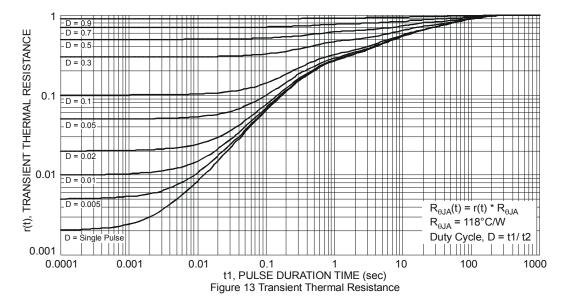


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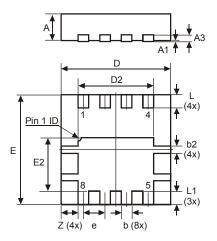
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Package Outline Dimensions

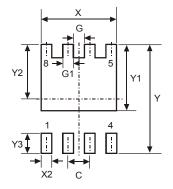
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI [®] 3333-8						
Dim	Min Max		Тур			
D	3.25	3.35	3.30			
Е	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E2	1.56	1.66	1.61			
Α	0.75	0.85	0.80			
A1	0	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	-	_	0.20			
L	0.35	0.45	0.40			
L1	_	_	0.39			
е	_	_	0.65			
Ζ	_	_	0.515			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
Х	2.370			
X2	0.420			

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